# **Lab 3 Instructions**

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### **Components**

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- Transistor BJT 2N3904
- Resistor  $R_L = 3.9 \text{ k}\Omega$
- Resistor  $R_c$ ,  $R_e$ ,  $R_1$  and  $R_2$ 
  - According to calculations
- Capacitors
  - $2 \times 1 \mu F$
  - $2 \times 47 \mu F$

## **Objectives**

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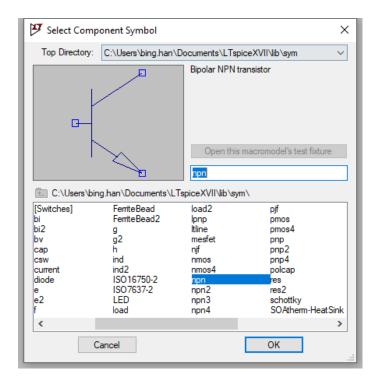
- Find  $\beta$  of the Transistor
- Simulate frequency response of a common emitter amplifier
- Simulate frequency response of a common collector amplifier



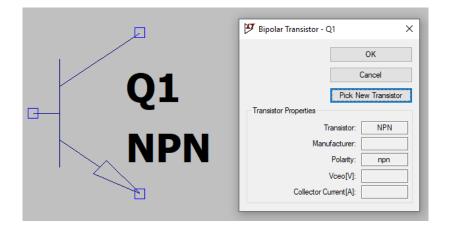
# Find $\beta$ of the Transistor

### **Find the Transistor**

Find the NPN transistor 2N3904

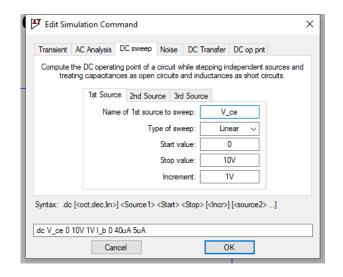


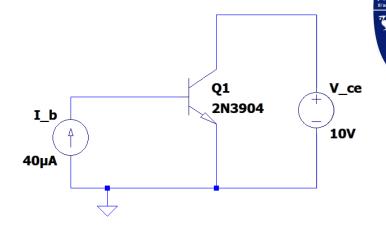


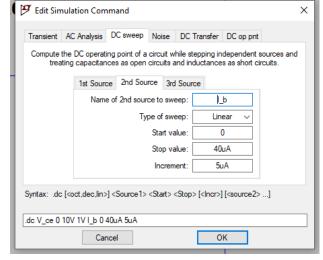


#### **Built the Circuit**

- Input the circuit schematic as follows
- Pull down the "Simulate" window, select "Edit Simulation Cmd"





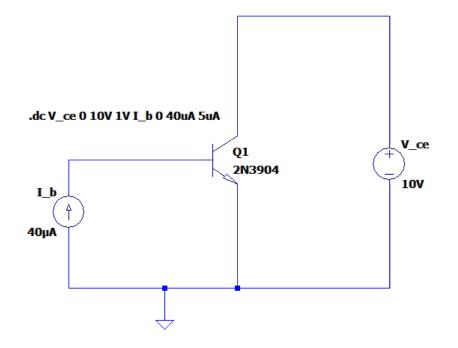


## Find $\beta$ of the Transistor

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- Set the value of  $I_B$ 
  - $0, 5, 10, \dots, 40 \mu A$
- Set the value of  $V_{CE}$ 
  - 0, 1, 2, · · · , 10 V
- The unit " $\mu$ A" is represented by 'uA' in LTSpice

• Calculate the dc current gain  $\beta$  at  $I_c = 5 \text{ mA}$ 



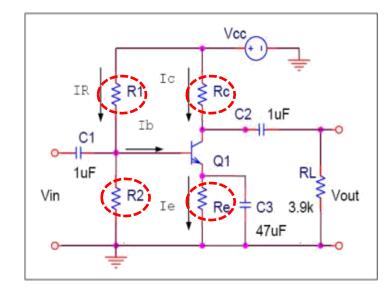


# **Common Emitter Amplifier**

## **Common Emitter Amplifier**

- Calculate the values of  $R_c$ ,  $R_e$ ,  $R_1$  and  $R_2$ 
  - DC Bias:  $V_{CC} = 10 \text{ V}, V_{CE} = 5 \text{ V}, I_{CQ} = 5 \text{ mA}$
- $R_1$  and  $R_2$  form a potential divider
  - Fix the base voltage of the transistor
- $I_R = 10I_{BQ}$ ,  $V_{BE} = 0.7 \text{ V}$
- R<sub>E</sub> helps to stabilize the bias
  - If the temperature increases, then extra collector current will flow.
  - If  $I_{CQ}$  increases, then  $I_{EQ}$  increases
  - $V_E$  increases, and reducing the effective base emitter voltage and therefore stabilizing the collector current.





### **Calculations**



- Assume  $V_E = \frac{1}{10} V_{CC}$ ,  $I_R = 10 I_{BQ}$ ,  $V_{CC} = 10$  V,  $V_{CE} = 5$  V,  $I_{CQ} = 5$  mA
- Determine  $R_C$ ,  $R_E$ ,  $R_1$  and  $R_2$

$$V_{CC} = I_{CQ}R_C + V_{CE} + I_{EQ}R_E$$

$$I_{CQ} \cong I_{EQ}$$

$$V_B = V_E + 0.7$$

$$R_1 = \frac{V_{CC} - V_B}{I_R} = \frac{V_{CC} - V_B}{10I_{BO}}$$

$$R_2 = \frac{V_B}{9I_{BO}}$$

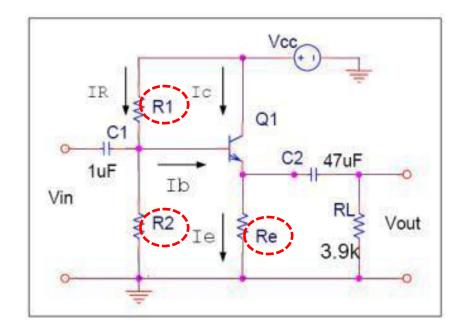


# **Common Collector Amplifier**

## **Common Collector Amplifier**

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- Calculate the values of  $R_E$ ,  $R_1$  and  $R_2$ 
  - DC Bias:  $V_{CC} = 10 \text{ V}, V_{CE} = 5 \text{ V}, I_C = 5 \text{ mA}$
- R<sub>1</sub> and R<sub>2</sub> form a potential divider
  - Fix the base voltage of the transistor



### **Calculations**



- Assume  $I_R = 10I_{BQ}$ ,  $V_{CC} = 10 \text{ V}$ ,  $V_{CE} = 5 \text{ V}$ ,  $I_{CQ} = 5 \text{ mA}$
- Determine  $R_E$ ,  $R_1$  and  $R_2$

$$V_{CC} = V_{CE} + I_{EQ}R_E$$
$$I_{CQ} \cong I_{EQ}$$

$$V_B = V_E + 0.7$$

$$R_1 = \frac{V_{CC} - V_B}{I_R} = \frac{V_{CC} - V_B}{10I_{BO}} \qquad \qquad R_2 = \frac{V_B}{9I_{BQ}}$$